NSN 5961-01-029-4557

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-029-4557 **Inclosure Material:** Glass **Overall Length:** Between 0.230 inches and 0.300 inches **Terminal Length:** 1.000 inches **Overall Diameter:** Between 0.085 inches and 0.107 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 reverse voltage, peak **Current Rating Per Characteristic:** 10.00 microamperes forward current, average torr and 0.02 microamperes forward current, average peak **Power Rating Per Characteristic:** 400.0 milliwatts small-signal input power, common-collector absolute **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 80131-release6283 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: